



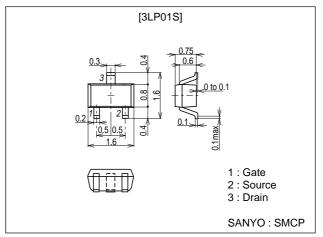
Ultrahigh-Speed Switching Applications

Features

- · Low ON-resistance.
- · Ultrahigh-speed switching.
- 2.5V drive.

Package Dimensions

unit : mm 2192



Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSS		-30	V
Gate-to-Source Voltage	VGSS		±10	V
Drain Current (DC)	ID		-0.1	Α
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	-0.4	Α
Allowable Power Dissipation	PD		0.15	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Drain-to-Source Breakdown Voltage	V(BR)DSS	I _D =-1mA, V _G S=0	-30			٧
Zero-Gate Voltage Drain Current	IDSS	V _{DS} =-30V, V _{GS} =0			-10	μΑ
Gate-to-Sourse Leakage Current	IGSS	V _{GS} =±8V, V _{DS} =0			±10	μΑ
Cutoff Voltage	VGS(off)	V _{DS} =-10V, I _D =-100μA	-0.4		-1.4	V
Forward Transfer Admittance	yfs	VDS=-10V, ID=-50mA	80	110		mS
Static Drain-to-Source On-State Resistance	R _{DS} (on)1	I _D =-50mA, V _G S=-4V		8	10.4	Ω
	R _{DS} (on)2	ID=-30mA, VGS=-2.5V		11	15.4	Ω
	RDS(on)3	ID=-1mA, VGS=-1.5V		27	54	Ω

Continued on next page.

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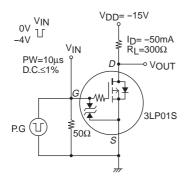
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Offic
Input Capacitance	Ciss	V _{DS} =-10V, f=1MHz		7.5		pF
Output Capacitance	Coss	V _{DS} =-10V, f=1MHz		5.7		pF
Reverse Transfer Capacitance	Crss	V _{DS} =-10V, f=1MHz		1.8		pF
Turn-ON Delay Time	t _d (on)	See specified Test Circuit		24		ns
Rise Time	t _r	See specified Test Circuit		55		ns
Turn-OFF Delay Time	t _d (off)	See specified Test Circuit		120		ns
Fall Time	t _f	See specified Test Circuit		130		ns
Total Gate Charge	Qg	V _{DS} =-10V, V _{GS} =-10V, I _D =-100mA		1.43		nC
Gate-to-Source Charge	Qgs	V _{DS} =-10V, V _{GS} =-10V, I _D =-100mA		0.18		nC
Gate-to-Drain "Miller" Charge	Qgd	V _{DS} =-10V, V _{GS} =-10V, I _D =-100mA		0.25		nC
Diode Forward Voltage	V _{SD}	I _S =-100mA, V _G S=0		-0.83	-1.2	V

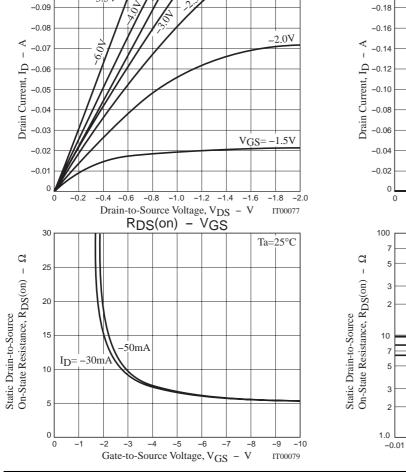
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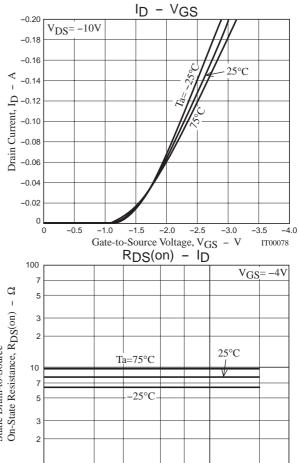
-0.10

Switching Time Test Circuit

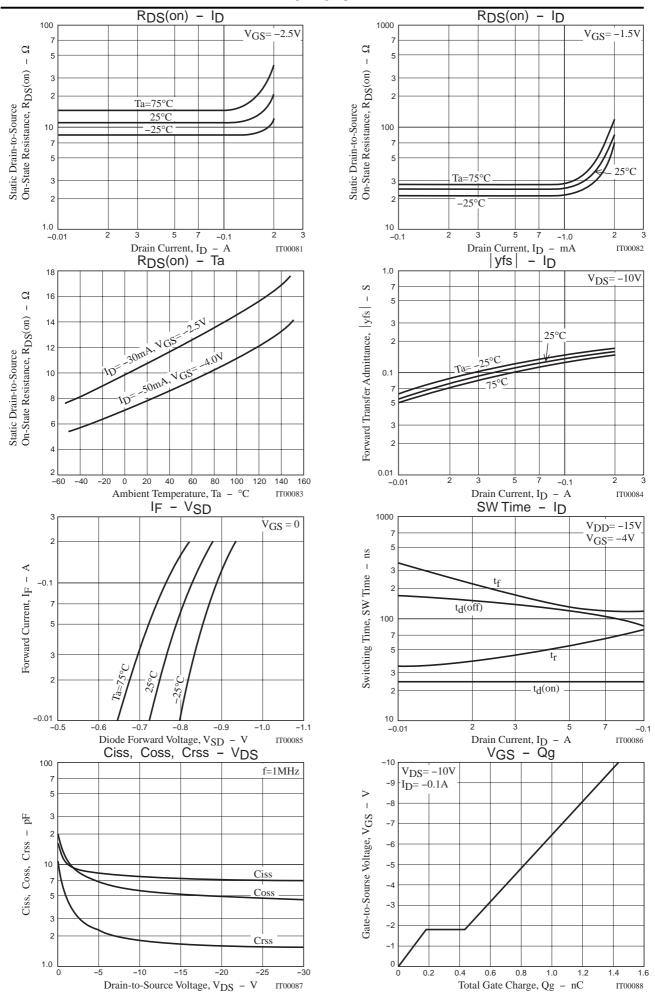


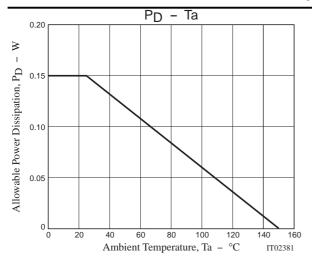
ID - VDS





Drain Current, I_D - A





Note on usage: Since the 3LP01S is designed for high-speed switching applications, please avoid using this device in the vicinity of highly charged objects.

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